

# FAIRCHILD

SEMICONDUCTOR®

May 1992 Bayiagd March

#### Revised March 2005

'4ABT244 Octal Buffer/Line Driver with 3-STATE Outputs

# 74ABT244 Octal Buffer/Line Driver with 3-STATE Outputs

#### **General Description**

The ABT244 is an octal buffer and line driver with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/ receiver.

#### Features

- Non-inverting buffers
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching, noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability
- Disable time less than enable time to avoid bus contention

## **Ordering Code:**

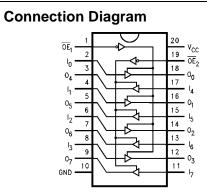
Order Number	Package	Package Description					
Order Number	Number	Package Description					
74ABT244CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide					
74ABT244CSJ	M20D	Pb-Free 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide					
74ABT244CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), JEDEC MO-150, 5.3mm Wide					
74ABT244CMSAX_NL (Note 1)	MSA20	Pb-Free 20-Lead Shrink Small Outline Package (SSOP), JEDEC MO-150, 5.3mm Wide					
74ABT244CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide					
74ABT244CMTCX_NL (Note 1)	MTC20	Pb-Free 20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide					
74ABT244CPC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide					
Device also available in Tape	Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.						

Pb-Free package per JEDEC J-STD-020B.

Note 1: "\_NL" indicates Pb-Free package (per JEDEC J-STD-020B). Device available in Tape and Reel only.







# **Pin Descriptions**

Pin Names	Description
$\overline{OE}_1, \overline{OE}_2$	Output Enable Input
	(Active LOW)
I <sub>0</sub> —I <sub>7</sub>	Inputs
O <sub>0</sub> –O <sub>7</sub>	Outputs

## **Truth Table**

OE <sub>1</sub>	I <sub>0-3</sub>	0 <sub>0-3</sub>	OE <sub>2</sub>	I <sub>4-7</sub>	0 <sub>4-7</sub>
Н	Х	Z	Н	Х	Z
L	н	н	L	н	н
L	L	L	L	L	L

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial Z = High Impedance

# Absolute Maximum Ratings(Note 2)

	-
Storage Temperature	-65°C to +150°C
Ambient Temperature under Bias	-55°C to +125°C
Junction Temperature under Bias	–55°C to +150°C
V <sub>CC</sub> Pin Potential to Ground Pin	-0.5V to +7.0V
Input Voltage (Note 3)	-0.5V to +7.0V
Input Current (Note 3)	-30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	-0.5V to 5.5V
in the HIGH State	–0.5V to V <sub>CC</sub>
Current Applied to Output	
in LOW State (Max)	twice the rated I <sub>OL</sub> (mA)
DC Latchup Source Current	–500 mA
Over Voltage Latchup (I/O)	10V

# Recommended Operating Conditions

Free Air Ambient Temperature	-40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate ( $\Delta V/\Delta t$ )	
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

# **DC Electrical Characteristics**

Symbol	Param	eter	Min	Тур	Max	Units	V <sub>CC</sub>	Conditions
V <sub>IH</sub>	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V <sub>IL</sub>	Input LOW Voltage				0.8	V		Recognized LOW Signal
V <sub>CD</sub>	Input Clamp Diode Vo	oltage			-1.2	V	Min	I <sub>IN</sub> = -18 mA
V <sub>OH</sub>	Output HIGH Voltage		2.5			V	Min	$I_{OH} = -3 \text{ mA}$
			2.0			V	Min	$I_{OH} = -32 \text{ mA}$
V <sub>OL</sub>	Output LOW Voltage				0.55			I <sub>OL</sub> = 64 mA
IIH	Input HIGH Current				1	μA	Max	V <sub>IN</sub> = 2.7V (Note 5)
					1			$V_{IN} = V_{CC}$
I <sub>BVI</sub>	Input HIGH Current B	reakdown Test			7	μA	Max	V <sub>IN</sub> = 7.0V
I <sub>IL</sub>	Input LOW Current				-1		Max	V <sub>IN</sub> = 0.5V (Note 5)
					-1	μA	IVIAX	$V_{IN} = 0.0V$
V <sub>ID</sub>	Input Leakage Test		4.75			V	0.0	I <sub>ID</sub> = 1.9 μA
								All Other Pins Grounded
I <sub>OZH</sub>	Output Leakage Curre	ent			10	μA	0 – 5.5V	$V_{OUT} = 2.7V; \overline{OE}_n = 2.0V$
I <sub>OZL</sub>	Output Leakage Curre	ent			-10	μA	0 – 5.5V	$V_{OUT} = 0.5V; \overline{OE}_n = 2.0V$
I <sub>OS</sub>	Output Short-Circuit C	Current	-100		-275	mA	Max	$V_{OUT} = 0.0V$
I <sub>CEX</sub>	Output High Leakage	Current			50	μA	Max	V <sub>OUT</sub> = V <sub>CC</sub>
I <sub>ZZ</sub>	Bus Drainage Test				100	μA	0.0	$V_{OUT} = 5.5V$ ; All Others GND
I <sub>CCH</sub>	Power Supply Curren	t			50	μA	Max	All Outputs HIGH
I <sub>CCL</sub>	Power Supply Current	t			30	mA	Max	All Outputs LOW
I <sub>CCZ</sub>	Power Supply Curren	t			50	μA	Max	$\overline{OE}_n = V_{CC}$ ,
								All Others at V <sub>CC</sub> or Ground
I <sub>CCT</sub>	Additional I <sub>CC</sub> /Input	Outputs Enabled			2.5	mA		$V_{I} = V_{CC} - 2.1V$
		Outputs 3-STATE			2.5	mA	Max	Enable Input V <sub>I</sub> = V <sub>CC</sub> - 2.1V
		Outputs 3-STATE			50	μA		Data Input V <sub>I</sub> = V <sub>CC</sub> - 2.1V
								All Others at V <sub>CC</sub> or Ground
I <sub>CCD</sub>	Dynamic I <sub>CC</sub>	No Load				mA/		Outputs OPEN
	(Note 5)				0.1	MHz	Max	$\overline{OE}_n = GND$ , (Note 4)
								One Bit Toggling, 50% Duty Cycle

Note 4: For 8 bits toggling, I<sub>CCD</sub> < 0.8 mA/MHz.

Note 5: Guaranteed, but not tested.

Ņ
4
N
F
മ
◄
4
r

#### **DC Electrical Characteristics**

(SOIC pa	(SOIC package)						
							Conditions
Symbol	Parameter	Min	Тур	Max	Units	Vcc	C <sub>L</sub> = 50 pF,
							$\mathbf{R_L} = 500\Omega$
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>		0.5	0.8	V	5.0	T <sub>A</sub> = 25°C (Note 6)
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	-1.3	-0.8		V	5.0	T <sub>A</sub> = 25°C (Note 6)
V <sub>OHV</sub>	Minimum HIGH Level Dynamic Output Voltage	2.7	3.1		V	5.0	T <sub>A</sub> = 25°C (Note 8)
V <sub>IHD</sub>	Minimum HIGH Level Dynamic Input Voltage	2.0	1.5		V	5.0	T <sub>A</sub> = 25°C (Note 7)
VILD	Maximum LOW Level Dynamic Input Voltage		1.1	0.8	V	5.0	T <sub>A</sub> = 25°C (Note 7)

Note 6: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 7: Max number of data inputs (n) switching. n - 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (VILD), 0V to threshold (VIHD). Guaranteed, but not tested.

Note 8: Max number of outputs defined as (n). n - 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

#### **AC Electrical Characteristics**

(SOIC and SSOP package)

Symbol	Parameter	$T_A = +25^{\circ}C$ $V_{CC} = +5V$ $C_L = 50 \text{ pF}$		$T_{A} = -55^{\circ}C \text{ to } +125^{\circ}C$ $V_{CC} = 4.5V - 5.5V$ $C_{L} = 50 \text{ pF}$		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ $V_{CC} = 4.5V - 5.5V$ $C_L = 50 \text{ pF}$		Units	
		Min	Тур	Max	Min	Max	Min	Max	
t <sub>PLH</sub>	Propagation Delay	1.0	2.5	3.6	1.0	5.3	1.0	3.6	
t <sub>PHL</sub>	Data to Outputs	1.0	2.3	3.6	1.0	5.0	1.0	3.6	ns
t <sub>PZH</sub>	Output Enable	1.5	3.5	6.0	0.8	6.5	1.5	6.0	50
t <sub>PZL</sub>	Time	1.5	3.6	6.0	1.2	7.9	1.5	6.0	ns
t <sub>PHZ</sub>	Output Disable	1.7	3.5	5.6	1.2	7.6	1.7	5.6	ns
t <sub>PLZ</sub>	Time	1.7	3.3	5.6	1.0	7.9	1.7	5.6	115

#### **Extended AC Electrical Characteristics**

(SOIC package)

(00.0 pac		Т	-40°C to +8	E0C	T. 40%	C to +85°C	T. 40%	C to +85°C	
		I A	-40 °C to +8	5.0	$I_{A} = -40^{\circ}$	C to +85°C	$I_{A} = -40^{-1}$	C tO +85°C	
		V.	$V_{CC} = 4.5V - 5.5V$			$V_{CC}=4.5V5.5V$		$V_{CC} = 4.5V - 5.5V$	
Symbol Parameter			C <sub>L</sub> = 50 pF			C <sub>L</sub> = 250 pF		C <sub>L</sub> = 250 pF	
		8 Oi			1 Output Switching		8 Outputs Switching		
					(Note 10)		(Note 11)		
		Min	Тур	Max	Min	Max	Min	Max	
f <sub>TOGGLE</sub>	Max Toggle Frequency		100						MHz
t <sub>PLH</sub>	Propagation Delay	1.5		5.0	1.5	6.0	2.5	8.5	ns
t <sub>PHL</sub>	Data to Outputs	1.5		5.0	1.5	6.0	2.5	8.5	115
t <sub>PZH</sub>	Output Enable Time	1.5		6.5	2.5	7.5	2.5	10.0	20
t <sub>PZL</sub>		1.5		6.5	2.5	7.5	2.5	12.0	ns
t <sub>PHZ</sub>	Output Disable Time	1.0		5.6	(Not	0 12)	(Not	0 12)	ns
t <sub>PLZ</sub>		1.0		5.6	(Note 12)		(Note 12)		115

Note 9: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 10: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 11: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 12: The 3-STATE delays are dominated by the RC network (500Ω, 250 pF) on the output and have been excluded from the datasheet.

Symbol	Parameter	$T_A = -40^\circ C \text{ to } +85^\circ C$ $V_{CC} = 4.5V - 5.5V$ $C_L = 50 \text{ pF}$ 8 Outputs Switching (Note 15)	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ $V_{CC} = 4.5V - 5.5V$ $C_L = 250 \text{ pF}$ 8 Outputs Switching (Note 16)	Units
		Мах	Max	
t <sub>OSHL</sub> (Note 13)	Pin to Pin Skew HL Transitions	0.8	1.8	ns
t <sub>OSLH</sub> (Note 13)	Pin to Pin Skew LH Transitions	0.8	1.8	ns
t <sub>PS</sub> (Note 17)	Duty Cycle LH–HL Skew	1.0	2.5	ns
t <sub>OST</sub> (Note 13)	Pin to Pin Skew LH/HL Transitions	1.0	2.5	ns
t <sub>PV</sub> (Note 14)	Device to Device Skew LH/HL Transitions	1.5	3.0	ns

Note 13: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW (t<sub>OSHL</sub>), LOW-to-HIGH (t<sub>OSLH</sub>), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (t<sub>OST</sub>). The specification is guaranteed but not tested.

Note 14: Propagation delay variation for a given set of conditions (i.e., temperature and V<sub>CC</sub>) from device to device. This specification is guaranteed but not

tested.

Note 15: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.)

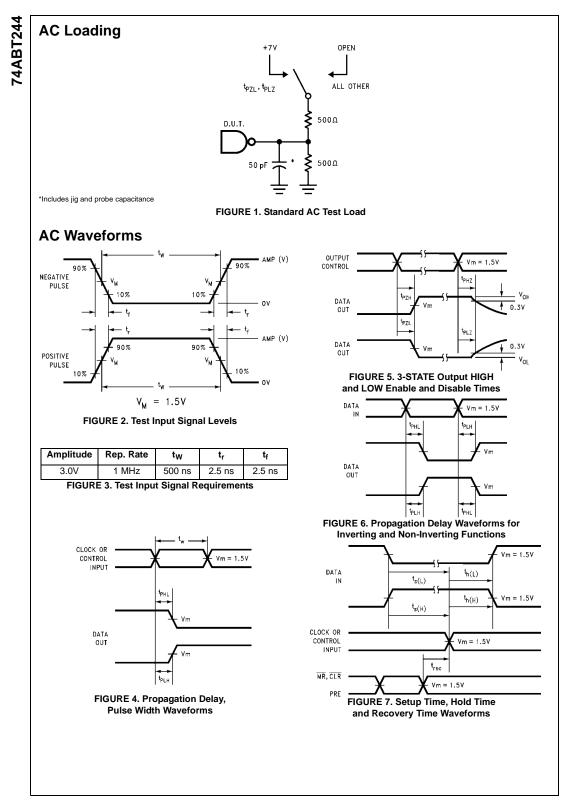
Note 16: These specifications guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 17: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

#### Capacitance

Symbol	Parameter	Тур	Units	Conditions T <sub>A</sub> = 25°C
C <sub>IN</sub>	Input Capacitance	5.0	pF	$V_{CC} = 0V$
C <sub>OUT</sub> (Note 18)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

Note 18:  $C_{OUT}$  is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.



www.fairchildsemi.com

